

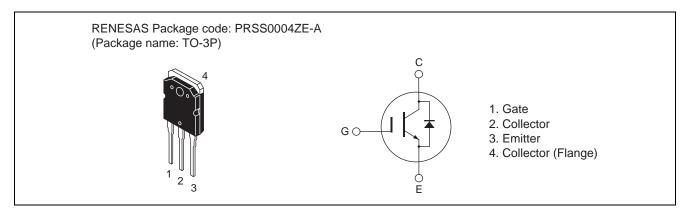
RJH60F7ADPK

Silicon N Channel IGBT High Speed Power Switching R07DS0237EJ0300 (Previous: REJ03G1837-0200) Rev.3.00 Jan 05, 2011

Features

- Low collector to emitter saturation voltage $V_{CE(sat)}=1.35$ V typ. (at $I_C=50$ A, $V_{GE}=15$ V, Ta=25°C)
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology
- High speed switching $t_f=74 \text{ ns typ. (at } I_C=30 \text{ A, } V_{CE}=400 \text{ V, } V_{GE}=15 \text{ V, } Rg=5 \Omega \text{, } Ta=25 ^{\circ}\text{C, inductive load)}$

Outline



Absolute Maximum Ratings

 $(Tc = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage		V _{CES}	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25°C	Ic	90	А
	Tc = 100°C	Ic	50	А
Collector peak current		ic(peak) Note1	180	А
Collector to emitter diode forward peak current		i _{DF} (peak) Note2	100	А
Collector dissipation		Pc	328.9	W
Junction to case thermal impedance (IGBT)		θј-с	0.38	°C/W
Junction to case thermal impedance (Diode)		θј-с	2.0	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. Pulse width limited by safe operating area.

2. $PW \le 5 \mu s$, duty cycle $\le 1\%$

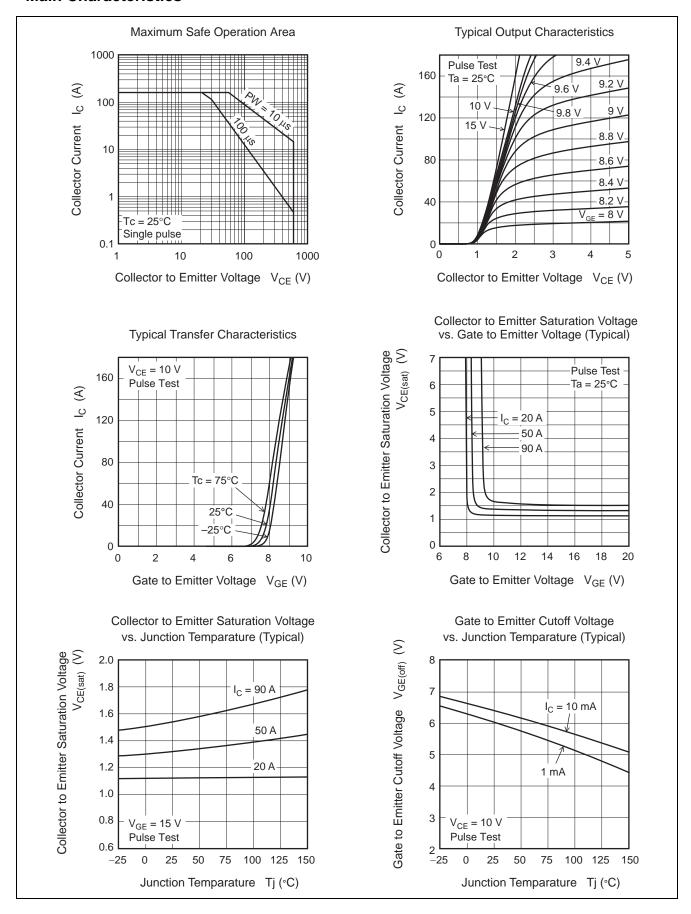
Electrical Characteristics

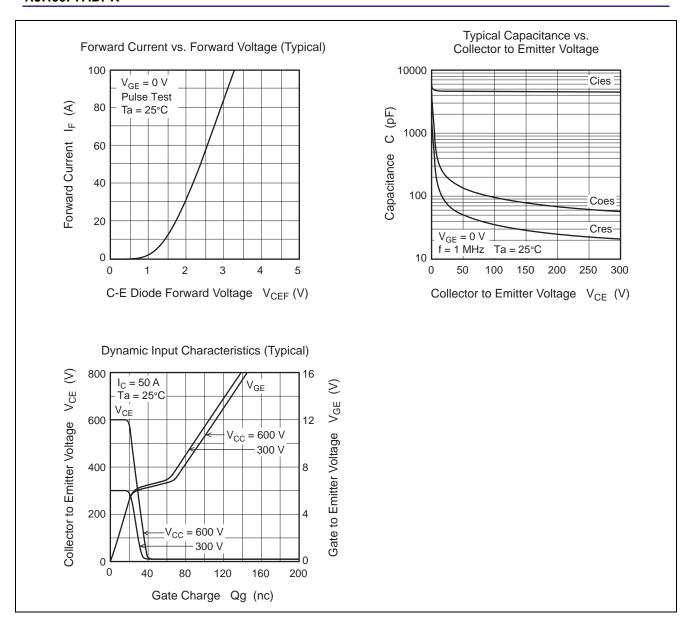
 $(Tj = 25^{\circ}C)$

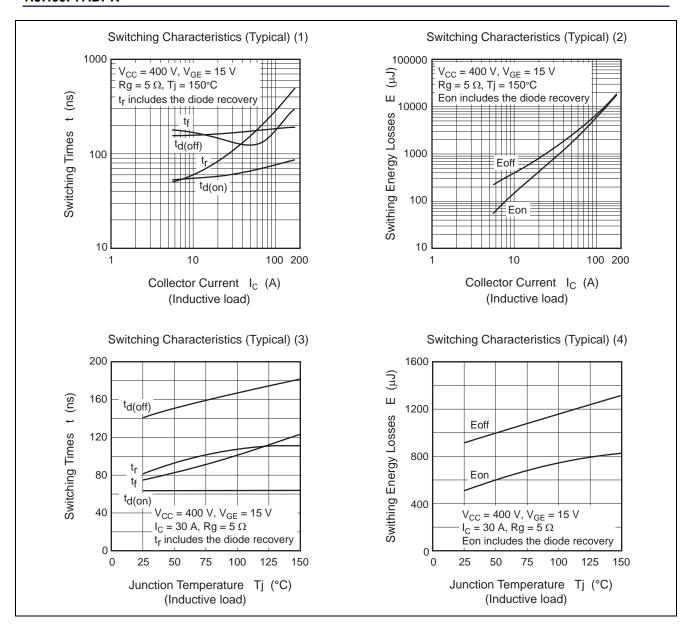
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}	_	_	100	μΑ	$V_{CE} = 600V, V_{GE} = 0$
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{\text{GE(off)}}$	4	_	8	V	$V_{CE} = 10V, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.35	1.75	V	$I_C = 50 \text{ A}, V_{GE} = 15 \text{V}^{\text{Note3}}$
	V _{CE(sat)}	_	1.6	_	V	$I_C = 90 \text{ A}, V_{GE} = 15V^{\text{Note3}}$
Input capacitance	Cies	_	4700	_	pF	V _{CE} = 25 V V _{GE} = 0 V f = 1 MHz
Output capacitance	Coes	_	198	_	pF	
Reverse transfer capacitance	Cres	_	83	_	pF	
Switching time	t _{d(on)}	_	63	_	ns	I_{C} = 30 A, V_{CE} = 400 V, V_{GE} = 15 V Rg = 5 Ω Note3 Inductive load
	t _r	_	81	_	ns	
	t _{d(off)}	_	142	_	ns	
	t _f	_	74	_	ns	
C-E diode forward voltage	V _{ECF1}	_	1.6	2.1	V	I _F = 20 A Note3
C-E diode reverse recovery time	t _{rr}	_	140	_	ns	I _F = 20 A
						$di_F/dt = 100 A/\mu s$

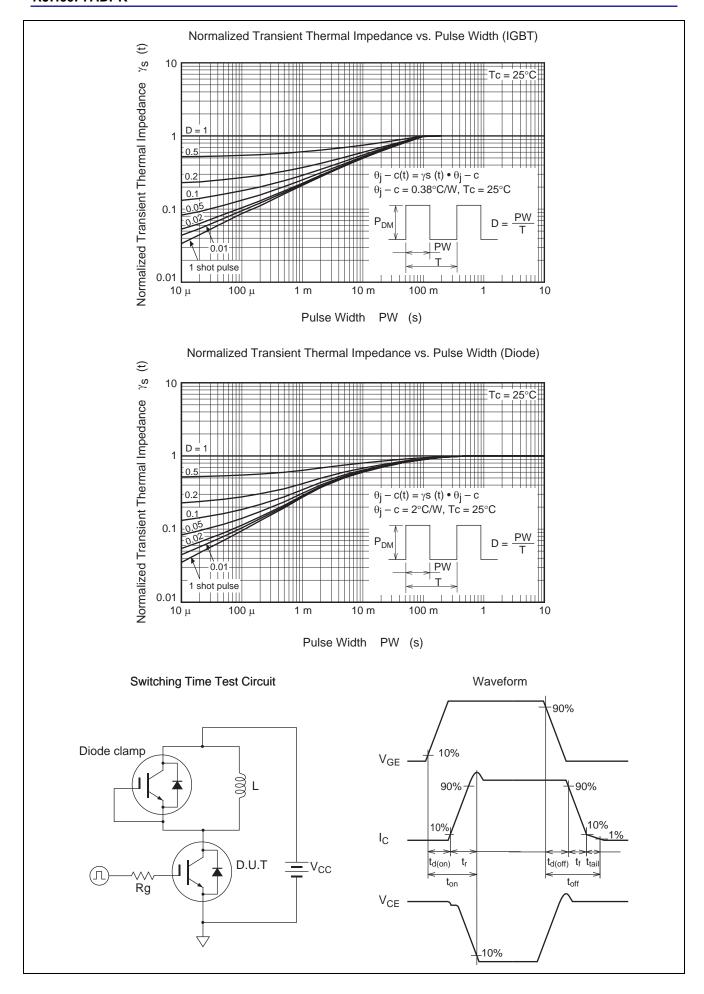
Notes: 3. Pulse test

Main Characteristics

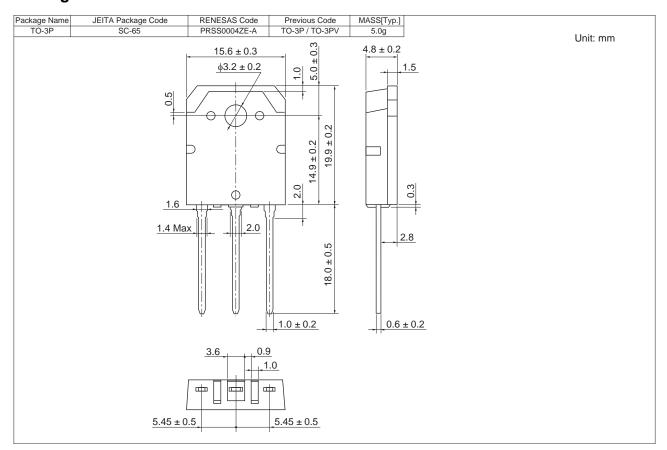








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container	
RJH60F7ADPK-00-T0	360 pcs	Box (Tube)	

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Renesas Electronics America Inc. 2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K Tel: +444-1628-585-100, Fax: +444-1628-585-900

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-2353-1155, Fax: +86-10-8235-7679

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 161F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2868-9318, Fax: +852-2886-9022/9044

Renesas Electronics Taiwan Co., Ltd. 7F, No. 363 Fu Shing North Road Taipei, Taiwa Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd. 1 harbourFront Avenue, #06-10, keppel Bay Tower, Singapore 098632 Tel: +65-6213-0200, Fax: +65-6278-8001

Renesas Electronics Malaysia Sdn.Bhd.
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd. 11F., Samik Lavied' or Bidg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea Tel: 482-2-558-3737, Fax: 482-2-558-5141

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